

GN1A - GN13

PRV : 50 - 1000 Volts
Io : 1.0 Ampere

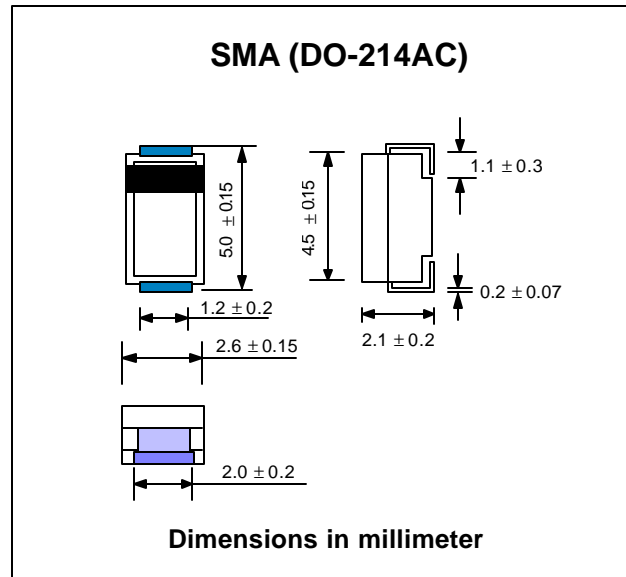
FEATURES :

- * Glass passivated chip
- * High current capability
- * High reliability
- * Low reverse current
- * Low forward voltage drop

MECHANICAL DATA :

- * Case : SMA Molded plastic
- * Epoxy : UL94V-O rate flame retardant
- * Lead : Lead Formed for Surface Mount
- * Polarity : Color band denotes cathode end
- * Mounting position : Any
- * Weight : 0.064 gram

GLASS PASSIVATED JUNCTION SILICON SURFACE MOUNT



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25 °C ambient temperature unless otherwise specified.
 Single phase, half wave, 60 Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

RATING	SYMBOL	GN1A	GN1B	GN1D	GN1G	GN1J	GN1K	GN1M	GN13	UNIT
Maximum Repetitive Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	1300	Volts
Maximum RMS Voltage	V _{RMS}	35	70	140	280	420	560	700	910	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	1300	Volts
Maximum Average Forward Current Ta = 75 °C	I _{F(AV)}	1.0								Amp.
Peak Forward Surge Current 8.3ms Single half sine wave Superimposed on rated load (JEDEC Method)	I _{FSM}	30								Amps.
Maximum Forward Voltage at I _F = 1.0 Amp.	V _F	1.0								Volts
Maximum DC Reverse Current Ta = 25 °C at rated DC Blocking Voltage Ta = 100 °C	I _R	5.0								μA
	I _{R(H)}	50								μA
Typical Junction Capacitance (Note1)	C _J	8								pF
Junction Temperature Range	T _J	- 65 to + 150								°C
Storage Temperature Range	T _{STG}	- 65 to + 150								°C

Notes :

(1) Measured at 1.0 MHz and applied reverse voltage of 4.0V_{DC}

UPDATE : MAY 27, 1998

RATING AND CHARACTERISTIC CURVES (GN1A - GN13)

FIG.1 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

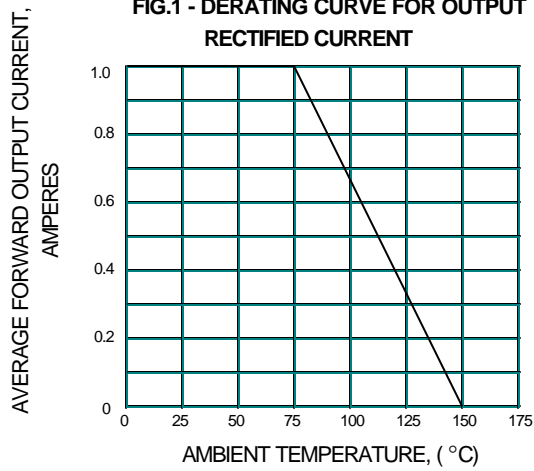


FIG.2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

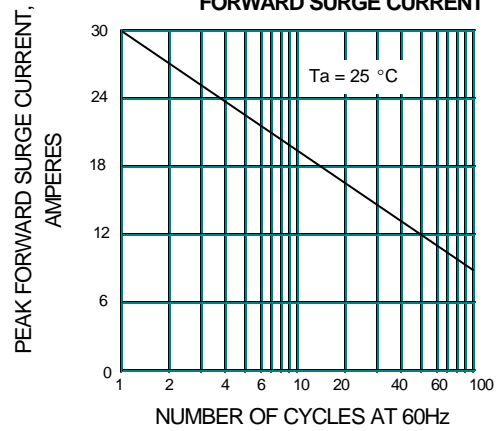


FIG.3 - TYPICAL FORWARD CHARACTERISTICS

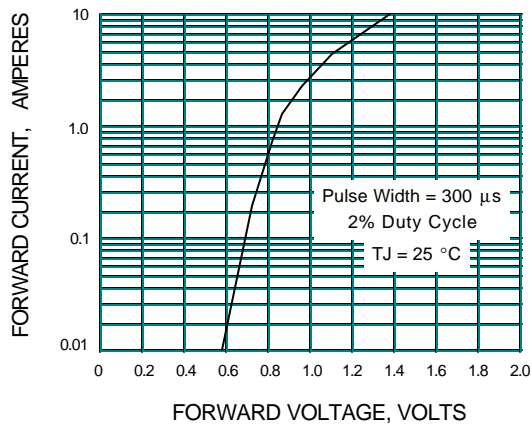


FIG.4 - TYPICAL REVERSE CHARACTERISTICS

